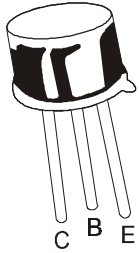


PNP SILICON POWER SWITCHING TRANSISTOR

2N3868



TO-39
Metal Can Package

Designed for High Speed, Medium Current Switching and High Frequency Amplifier Applications

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	VALUE	UNITS
Collector Emitter Voltage	V_{CEO}	60	V
Collector Base Voltage	V_{CBO}	60	V
Emitter Base Voltage	V_{EBO}	4.0	V
Collector Current - Continuous	I_C	3.0	A
Peak		10	A
Base Current	I_B	0.5	A
Power Dissipation at $T_c=25^\circ\text{C}$	P_D	6.0	W
Derate Above 25°C		34.3	mW/ $^\circ\text{C}$
Power Dissipation at $T_a=25^\circ\text{C}$	P_D	1.0	W
Derate Above 25°C		5.71	mW/ $^\circ\text{C}$
Operating And Storage Junction Temperature Range	T_j, T_{stg}	- 65 to +200	$^\circ\text{C}$

THERMAL CHARACTERISTICS

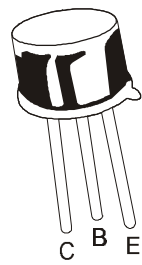
Junction to Case	$R_{th(j-c)}$	29	$^\circ\text{C/W}$
Junction to Ambient in free air	$R_{th(j-a)}$	175	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_c=25^\circ\text{C}$ unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNITS
Collector Emitter Voltage	V_{CEO}	$I_C=1\text{mA}, I_B=0$	60		V
Collector Base Voltage	V_{CBO}	$I_C=100\mu\text{A}, I_E=0$	60		V
Emitter Base Voltage	V_{EBO}	$I_E=100\mu\text{A}, I_C=0$	4.0		V
Collector Cut Off Current	I_{CEX}	$V_{CE}=60\text{V}, V_{BE(off)}=2\text{V}$		1.0	μA
Collector Cut off Current	I_{CBO}	$V_{CB}=60\text{V}, I_E=0, T_c=150^\circ\text{C}$		150	μA
DC Current Gain	$*h_{FE}$	$I_C=500\text{mA}, V_{CE}=1\text{V}$ $I_C=1.5\text{A}, V_{CE}=2\text{V}$ $I_C=2.5\text{A}, V_{CE}=3\text{V}$ $I_C=3\text{A}, V_{CE}=5\text{V}$	35 30 20 20	150	
Collector Emitter Saturation Voltage	$*V_{CE(sat)}$	$I_C=500\text{mA}, I_B=50\text{mA}$ $I_C=1.5\text{A}, I_B=150\text{mA}$ $I_C=2.5\text{A}, I_B=250\text{mA}$		0.50 0.75 1.30	V V V
Base Emitter Saturation Voltage	$*V_{BE(sat)}$	$I_C=500\text{mA}, I_B=50\text{mA}$ $I_C=1.5\text{A}, I_B=150\text{mA}$ $I_C=2.5\text{A}, I_B=250\text{mA}$	0.9	1.0 1.4 2.0	V V V

*Pulse Test: Pulse Width $\leq 300\text{ms}$, Duty Cycle $\leq 2\%$

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ELECTRICAL CHARACTERISTICS (T_c=25° C unless specified otherwise)

DYNAMIC CHARACTERISTICS

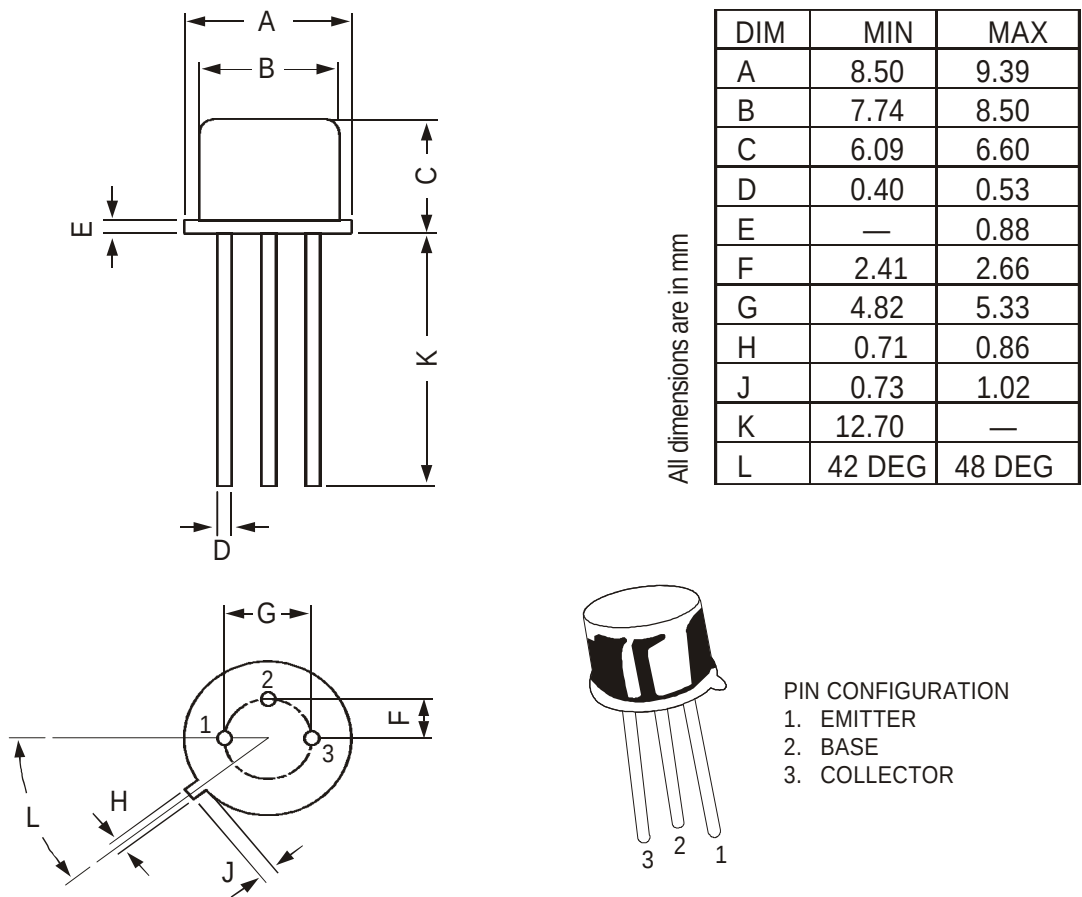
DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNITS
Current Gain Bandwidth Product	**f _T	I _C =100mA, V _{CE} =5V, f=20MHz	60		MHz
Output Capacitance	C _{ob}	V _{CB} =10V, I _E =0, f=0.1MHz		120	pF
Input Capacitance	C _{ib}	V _{EB} =3V, I _C =0, f=0.1MHz		1000	pF

SWITCHING CHARACTERISTICS

Delay Time	t _d	V _{CC} =30V, V _{BE(off)} =0, I _C =1.5A, I _{B1} =150mA		35	ns
Rise Time	t _r			65	ns
Storage Time	t _s	V _{CC} =30V, I _C =1.5A, I _{B1} =I _{B2} =150mA		325	ns
Fall Time	t _f			75	ns

** f_T = I_{hfe}/I_c. f_{test}

TO-39 Metal Can Package



Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight /Qty	Size	Qty	Size	Qty	Gr Wt
TO-39	500 pcs/polybag	540 gm /500 pcs	3" x 7.5" x 7.5"	20K	17" x 15" x 13.5"	32K	40 kgs

Component Disposal Instructions

1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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Continental Device India Limited

C-120 Naraina Industrial Area, New Delhi 110 028, India.

Telephone + 91-11-2579 6150, 5141 1112 Fax + 91-11-2579 5290, 5141 1119
email@cdil.com www.cdilsemi.com